TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANER TYPE

MT3S36FS

VCO OSCILLETOR STAGE
UHF LOW NOISE AMPLIFIER APPLICATION

FEATURES

- Low Noise Figure :NF=1.3dB (@f=2GHz)
- High Gain:|S21e|²=12.5dB (@f=2GHz)

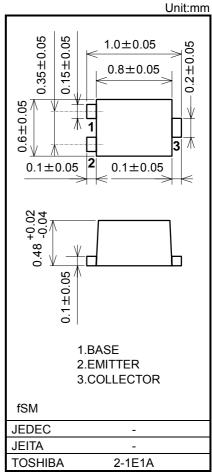
Marking



Maximum Ratings (Ta = 25°C)

| Characteristics | Symbol | Rating | Unit |
|-----------------------------|-----------------------|---------|------|
| Collector-Base voltage | V_{CBO} | 8 | V |
| Collector-Emitter voltage | V _{CEO} | 4.5 | V |
| Emitter-Base voltage | V _{EBO} | 1.5 | V |
| Collector-Current | IC | 36 | mA |
| Base-Current | ΙΒ | 18 | mA |
| Collector Power dissipation | P _C (Note) | 100 | mW |
| Junction temperature | Tj | 150 | °C |
| Storage temperature Range | T _{stg} | -55~150 | °C |

Note: Device mounted on a glass-epoxy PCB(0.88 cm 2 × 0.7 mm (t))



Weight: 0.0006 g



Microwave Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|----------------------|------------------------|---|-----|------|-----|------|
| Transition Frequency | fT | V _{CE} =3V, I _C =15mA, f=2GHz | 15 | 19 | - | GHz |
| Insertion Gain | S21e ² (1) | V _{CE} =3V, I _C =15mA, f=1GHz | 15 | 17.5 | - | dB |
| | S21e ² (2) | V _{CE} =3V, I _C =15mA, f=2GHz | 10 | 12.5 | - | dB |
| Noise Figure | NF(1) | V _{CE} =3V, I _C =3mA, f=1GHz | - | 1.1 | - | dB |
| | NF(2) | V _{CE} =3V, I _C =3mA, f=2GHz | - | 1.3 | 1.8 | dB |

Electrical Characteristics (Ta = 25°C)

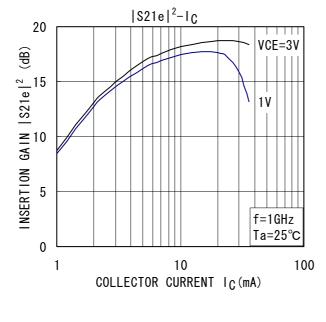
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|------------------|---|-----|------|------|------|
| Collector Cut-off Current | I _{CBO} | V _{CB} =8V, I _E =0 | - | - | 1 | μA |
| Emitter Cut-off Current | I _{EBO} | V _{EB} =1V, I _C =0 | - | - | 1 | μA |
| DC Current Gain | hFE | V _{CE} =3V, I _C =10mA | 70 | - | 140 | - |
| Output Capacitance | C _{ob} | V _{CB} =1V, I _E =0, f=1MHz | - | 0.37 | 0.60 | pF |
| Reverse Transistor Capacitance | C _{re} | V _{CB} =1V, I _E =0, f=1MHz (Note 1) | - | 0.21 | 0.40 | pF |

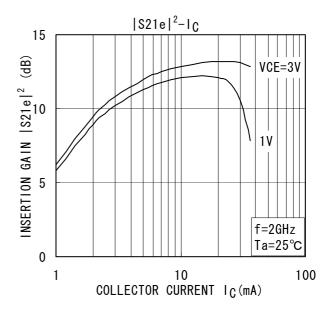
Note 1: Cre is measured by 3 terminal method with capacitance bridge.

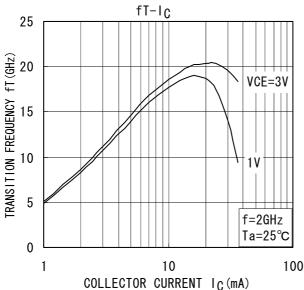
Caution: This device is sensitive to electrostatic discharge.

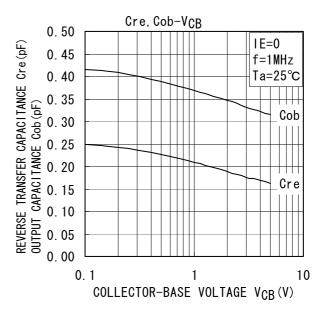
Please make enough tool and equipment earthed when you handle.

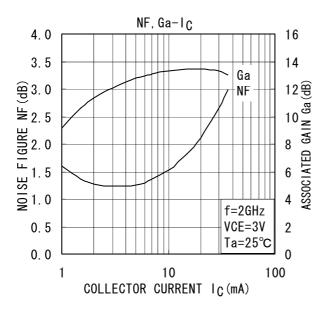
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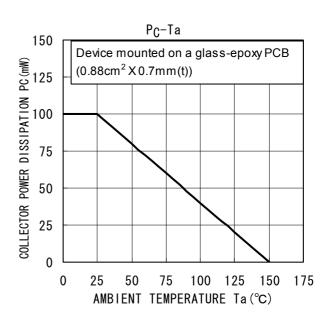












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